



GENERAL PURPOSE 100 mW GaAs MMIC AMPLIFIER, 0.8 - 3.8 GHz

Typical Applications

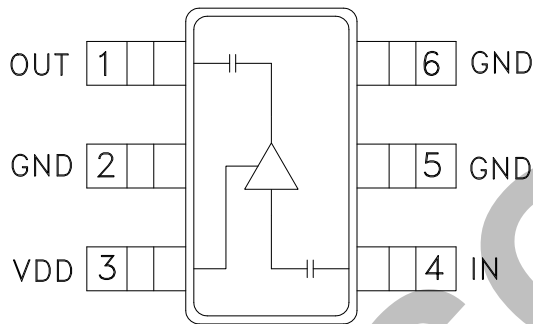
Broadband or Narrow Band Applications:

- Cellular/PCS/3G
- Fixed Wireless & Telematics
- Cable Modem Termination Systems
- WLAN, Bluetooth & RFID

Features

- Gain: 18 dB
- P1dB Output Power: +17 dBm@ +5V
- Single Supply: +3V or +5V
- No External Components
- Integrated DC Blocks
- Ultra Small Package: SOT26

Functional Diagram



General Description

The HMC308 & HMC308E are low cost MESFET MMIC amplifiers that operate from a single +3 to +5V supply from 0.8 to 3.8 GHz. The surface mount SOT26 amplifier can be used as a broadband amplifier stage or used with external matching for optimized narrow band applications. With Vdd biased at +5V, the HMC308 & HMC308E offers 18 dB of gain and +20 dBm of saturated output power while requiring only 53 mA of current. This amplifier is ideal as a driver amplifier for transmitters or for use as a local oscillator (LO) amplifier to increase drive levels for passive mixers. The amplifier occupies 0.014 in² (9 mm²), making it ideal for compact radio designs.

Electrical Specifications, $T_A = +25^\circ\text{C}$, as a function of Vdd

Parameter	Vdd = +3V			Vdd = +5V			Vdd = +5V			Vdd = +5V			Units
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
Frequency Range	2.3 - 2.7			0.8 - 2.3			2.3 - 2.7			2.7 - 3.8			GHz
Gain	13	15.5		14	18		13	16		10	13		dB
Gain Variation over Temperature		0.025	0.035		0.025	0.035		0.025	0.035		0.025	0.035	dB/°C
Input Return Loss		11			8			11			13		dB
Output Return Loss		17			13			12			13		dB
Output Power for 1 dB Compression (P1dB)	12	14		14	17		13.5	16.5		12	15		dBm
Saturated Output Power (Psat)		17			20			19.5			17		dBm
Output Third Order Intercept (IP3)	23	26		27	30		26	29		24	27		dBm
Noise Figure		7			7.5			7			7		dB
Supply Current (Idd)		50			53			53			53		mA

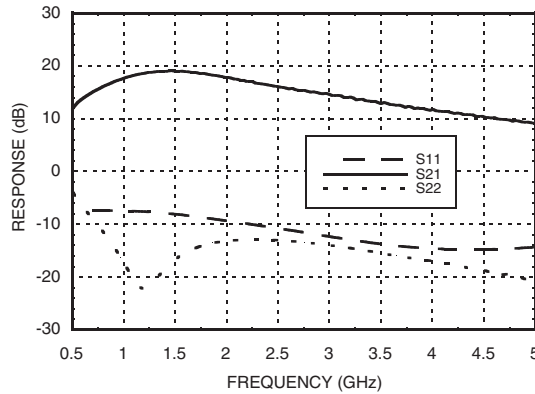
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For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

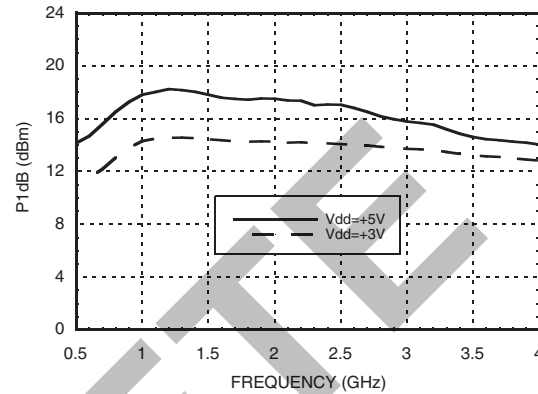


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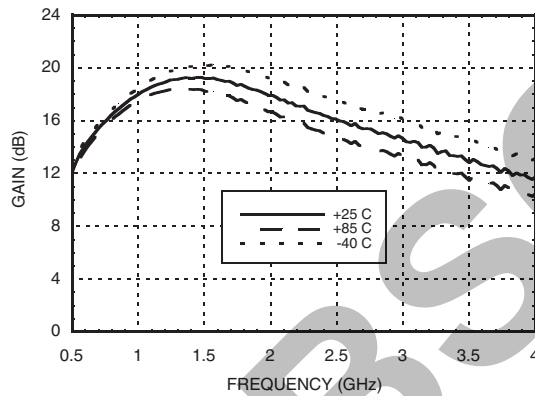
**Broadband Gain
& Return Loss @ Vdd = +5V**



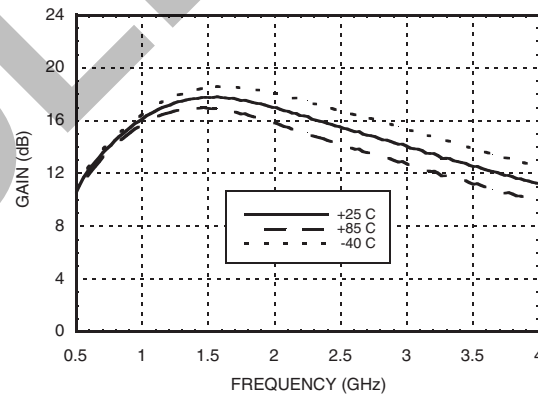
P1dB vs. Vdd Bias



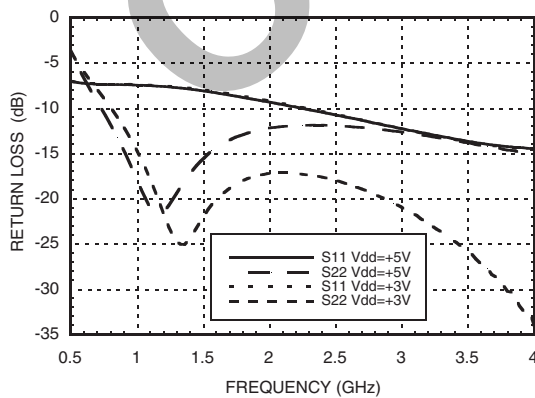
Gain vs. Temperature @ Vdd = +5V



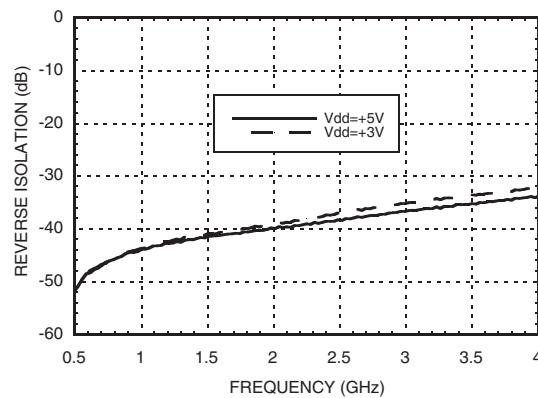
Gain vs. Temperature @ Vdd = +3V



**Input & Output
Return Loss vs. Vdd Bias**



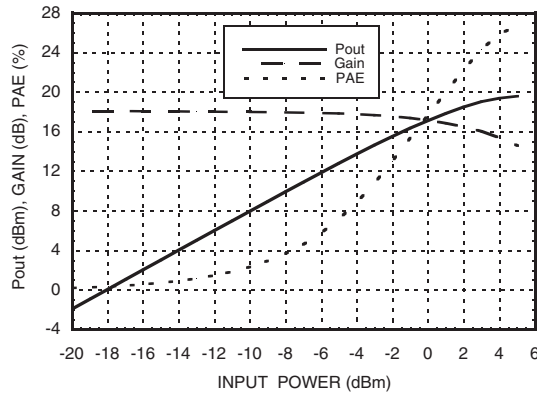
Reverse Isolation vs. Vdd Bias



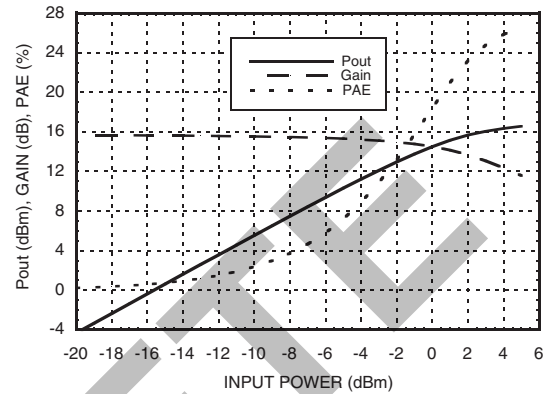


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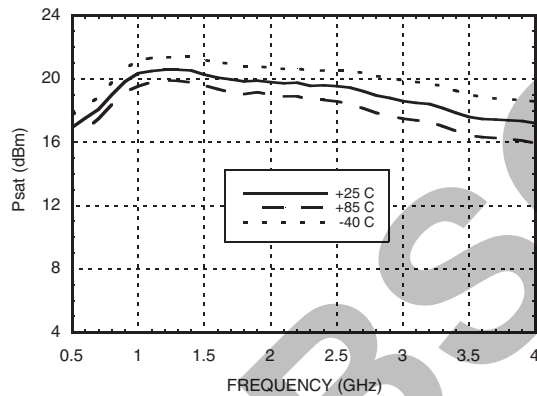
**Power Compression
@ 2.0 GHz, Vdd = +5V**



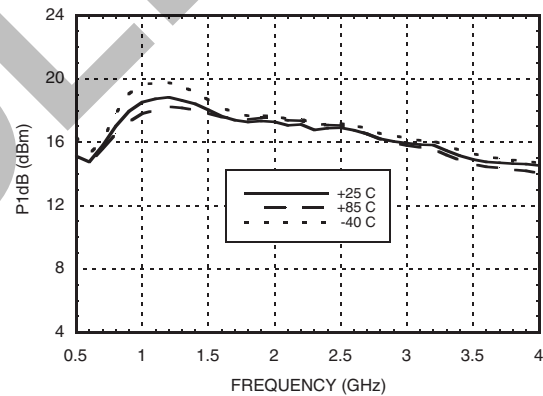
**Power Compression
@ 2.5 GHz, Vdd = +5V**



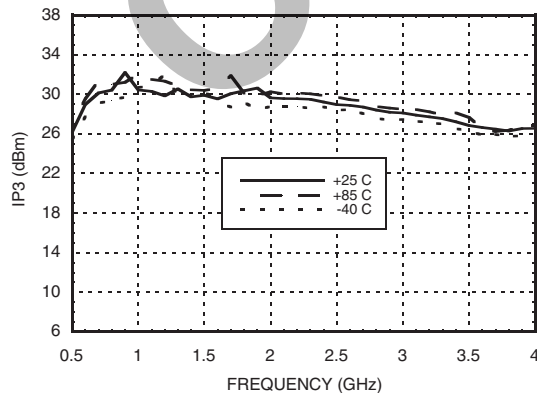
Psat vs. Temperature @ Vdd = +5V



**Output P1dB vs.
Temperature @ Vdd = +5V**

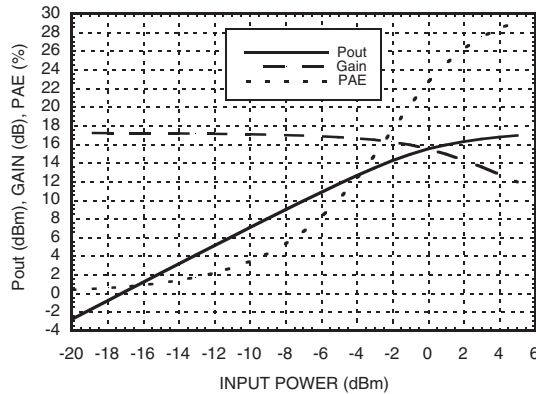
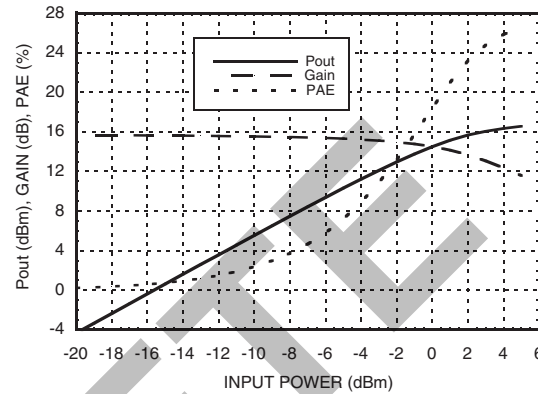
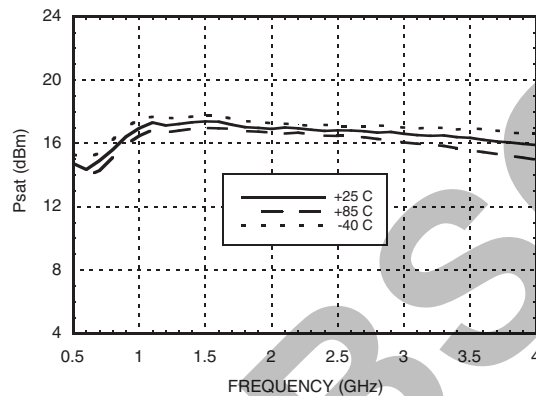
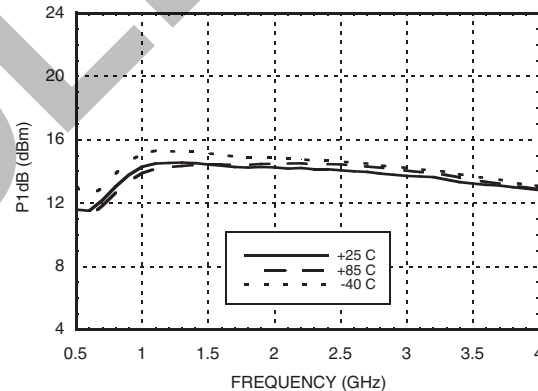
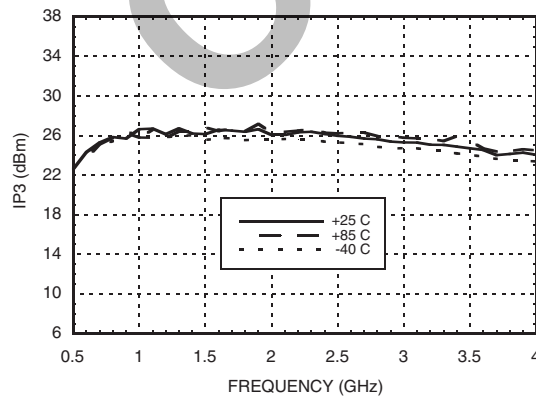


**Output IP3
vs. Temperature @ Vdd = +5V**



Typical Supply Current vs. Vdd

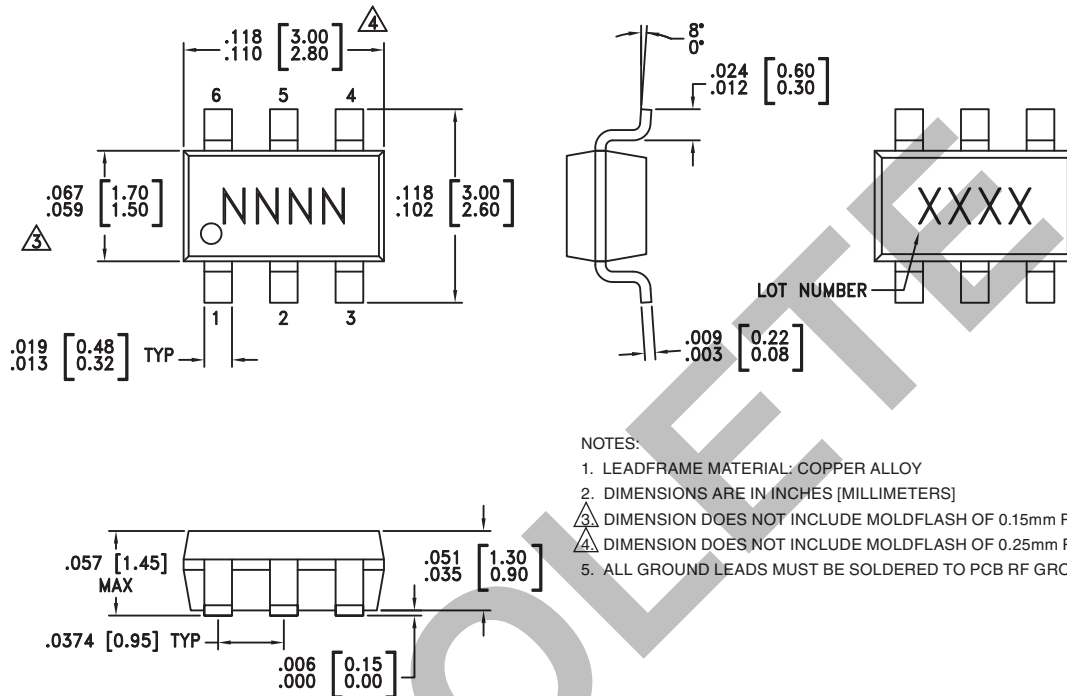
Vdd (Vdc)	Idd (mA)
+2.5	49
+3.0	50
+3.5	51
+4.5	50
+5.0	53
+5.5	54


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**Power Compression
@ 2.0 GHz, Vdd = +3V**

**Power Compression
@ 2.5 GHz, Vdd = +3V**

Psat vs. Temperature @ Vdd = +3V

**Output P1dB vs.
Temperature @ Vdd = +3V**

**Output IP3
vs. Temperature @ Vdd = +3V**

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7.0 Vdc
RF Input Power (RFIN)(Vdd = +5Vdc)	+10 dBm
Channel Temperature	150 °C
Continuous P _{diss} (T = 85 °C) (derate 6.25 mW/°C above 85 °C)	0.406 W
Thermal Resistance (channel to lead)	160 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

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Outline Drawing

Package Information



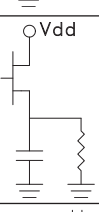
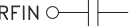
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC308	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H308 XXXX
HMC308E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	308E XXXX

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

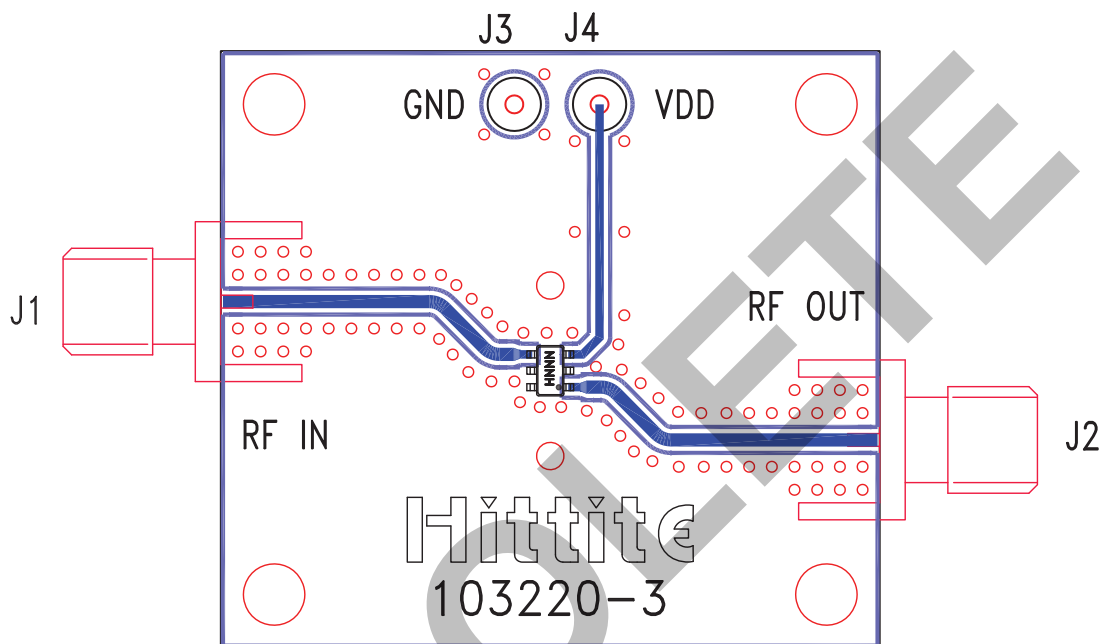
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
2, 5, 6	GND	These pins must be connected to RF/DC ground.	
3	Vdd	Power supply voltage.	
4	RFIN	This pin is AC coupled and matched to 50 Ohms.	

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Evaluation PCB



List of Materials for Evaluation PCB 103802 ^[1]

Item	Description
J1, J2	PCB Mount SMA Connector
J3, J4	DC Pins
U1	HMC308 / HMC308E Amplifier
PCB [2]	103220 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Roger 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.